

CR03AM-16A

800V - 0.3A - Thyristor

Low Power Use

R07DS0987EJ0500

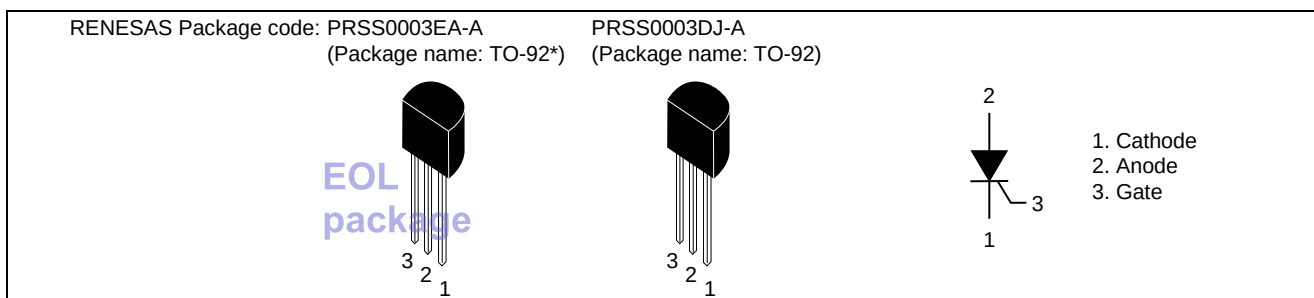
Rev.5.00

Feb. 22, 2022

Features

- $I_T(AV)$: 0.3 A
- V_{DRM} : 800 V
- I_{GT} : 100 μ A
- RoHS Compliant
- Planar Passivation Type
- Halogen-free (PRSS0003DJ-A)
- Completely Pb-free (PRSS0003DJ-A)

Outline



Application

Igniter, solid state relay, strobe flasher, circuit breaker, and other general purpose applications.

Maximum Ratings

Parameter	Symbol	Voltage class	Unit
		16	
Repetitive peak reverse voltage	V_{RRM}	800	V
Non-repetitive peak reverse voltage	V_{RSM}	960	V
DC reverse voltage	$V_{R(DC)}$	640	V
Repetitive peak off-state voltage ^{Note1}	V_{DRM}	800	V
Non-repetitive peak off-state voltage ^{Note1}	V_{DSM}	960	V
DC off-state voltage ^{Note1}	$V_{D(DC)}$	640	V

Notes: 1. With gate to cathode resistance $R_{GK}=1$ k Ω

Parameter	Symbol	Ratings	Unit	Conditions
RMS on-state current	$I_T(RMS)$	0.47	A	
Average on-state current	$I_T(AV)$	0.3	A	Commercial frequency, sine half wave 180°conduction, $T_a = 62^\circ\text{C}$
Surge on-state current	I_{TSM}	20	A	60 Hz sinewave 1 full cycle, peak value, non-repetitive
I^2t for fusing	I^2t	1.6	A ² s	Value corresponding to 1 cycle of half wave 60 Hz, surge on-state current
Peak gate power dissipation	P_{GM}	0.5	W	
Average gate power dissipation	$P_{G(AV)}$	0.1	W	
Peak gate forward voltage	V_{FGM}	6	V	
Peak gate reverse voltage	V_{RGM}	6	V	
Peak gate forward current	I_{FGM}	0.3	A	
Junction temperature	T_j	-40 to +125	°C	
Storage temperature	T_{stg}	-40 to +125	°C	

Electrical Characteristics

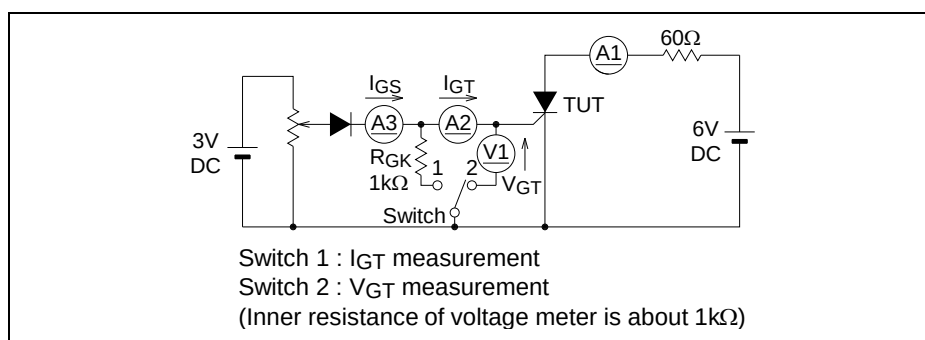
Parameter	Symbol	Min.	Typ.	Max.	Unit	Test conditions
Repetitive peak reverse current	I_{RRM}	—	—	0.1	mA	$T_j = 125^\circ\text{C}$, V_{RRM} applied
Repetitive peak off-state current	I_{DRM}	—	—	0.1	mA	$T_j = 125^\circ\text{C}$, V_{DRM} applied $R_{GK}=1\text{ k}\Omega$
On-state voltage	V_{TM}	—	—	1.8	V	$T_c = 25^\circ\text{C}$, $I_{TM} = 4\text{ A}$, instantaneous value
Gate trigger voltage	V_{GT}	—	—	0.8	V	$T_j = 25^\circ\text{C}$, $V_D = 6\text{ V}$, $I_T = 0.1\text{ A}$ ^{Note3}
Gate non-trigger voltage	V_{GD}	0.2	—	—	V	$T_j = 125^\circ\text{C}$, $V_D = 1/2 V_{DRM}$ $R_{GK}=1\text{ k}\Omega$
Gate trigger current	I_{GT}	1 ^{Note2}	—	100 ^{Note2}	μA	$T_j = 25^\circ\text{C}$, $V_D = 6\text{ V}$, $I_T = 0.1\text{ A}$ ^{Note3}
Holding current	I_H	—	—	3	mA	$T_j = 25^\circ\text{C}$, $V_D = 12\text{ V}$, $R_{GK}=1\text{ k}\Omega$
Thermal resistance	$R_{th(j-a)}$	—	—	180	$^\circ\text{C/W}$	Junction to ambient

Notes: 2. If special values of I_{GT} are required, choose item A, B, D or E from those listed in the table below.

Item	A	B	D	E
$I_{GT} (\mu\text{A})$	1 to 30	20 to 50	1 to 50	20 to 100

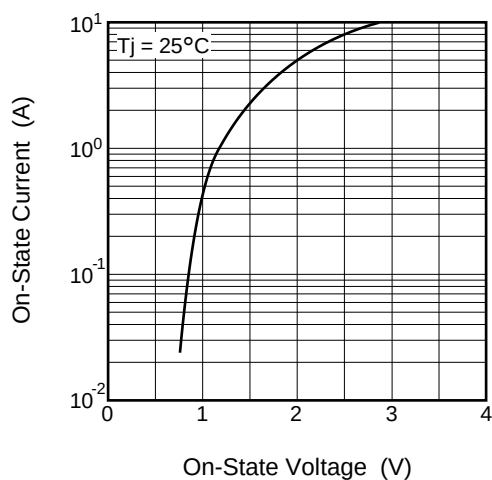
The above values do not include the current flowing through the $1\text{ k}\Omega$ resistance between the gate and cathode.

3. I_{GT} , V_{GT} measurement circuit.

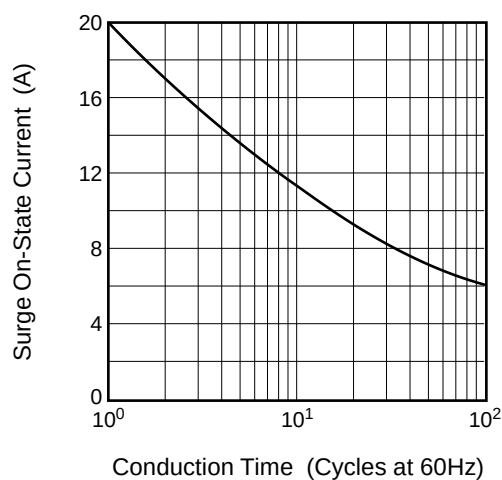


Performance Curves

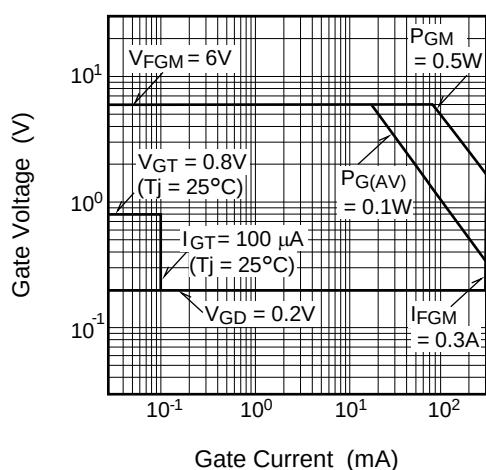
Maximum On-State Characteristics



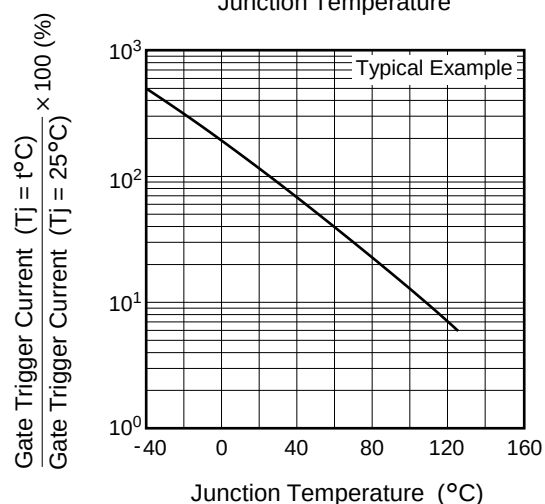
Rated Surge On-State Current



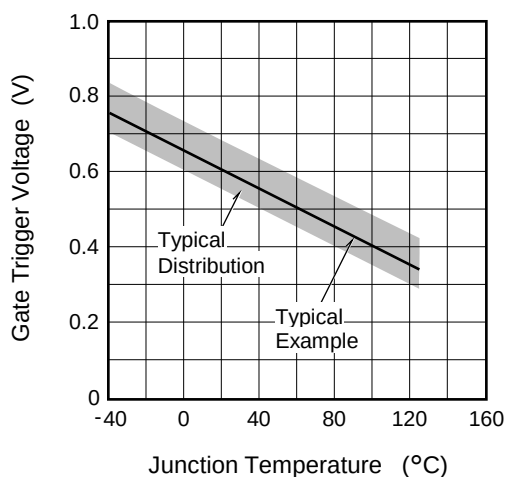
Gate Characteristics



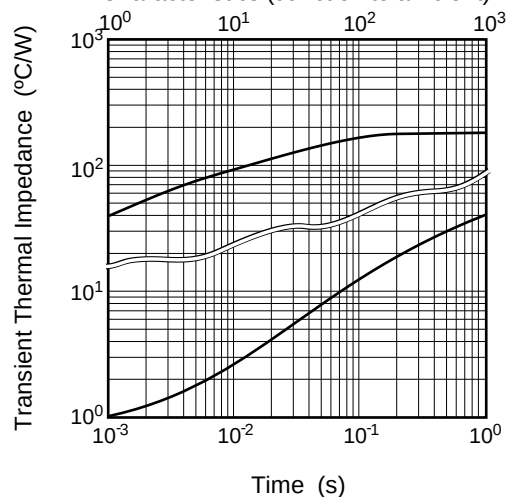
Gate Trigger Current vs. Junction Temperature



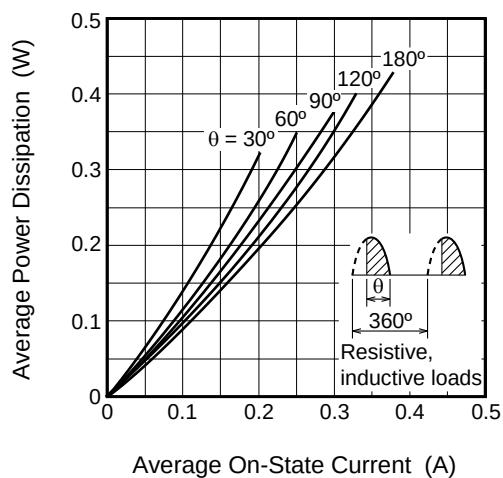
Gate Trigger Voltage vs. Junction Temperature



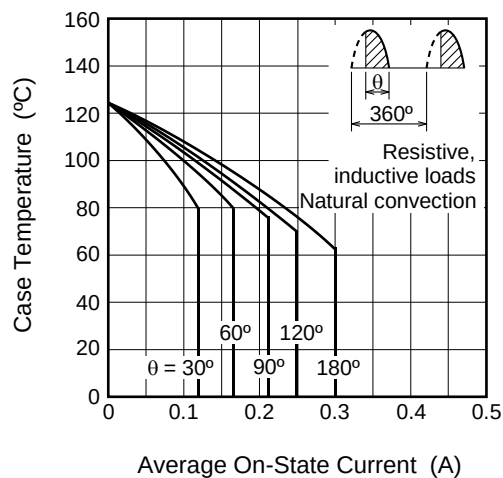
Maximum Transient Thermal Impedance Characteristics (Junction to ambient)



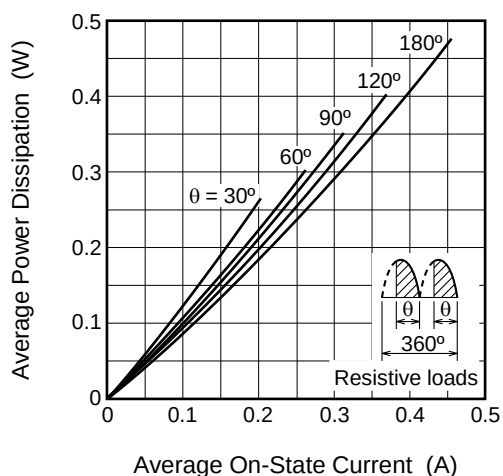
Maximum Average Power Dissipation
(Single-Phase Half Wave)



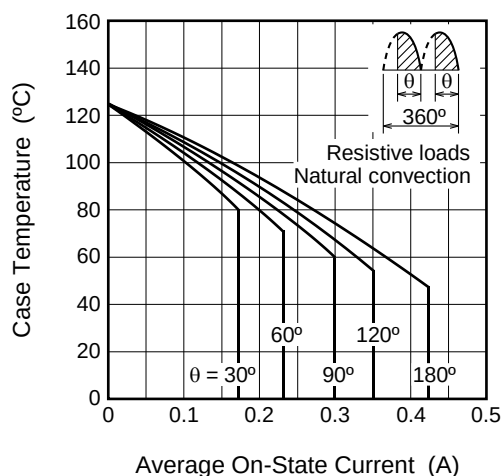
Allowable Case Temperature vs.
Average On-State Current
(Single-Phase Half Wave)



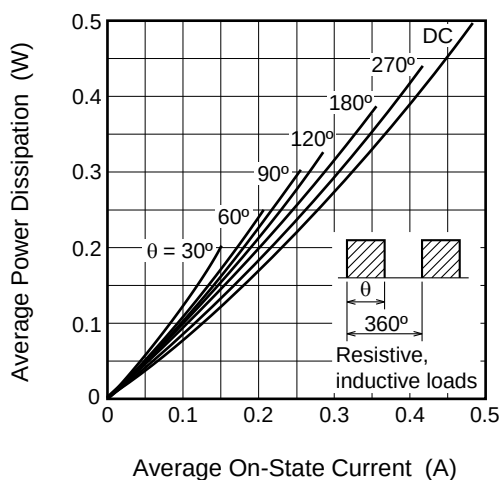
Maximum Average Power Dissipation
(Single-Phase Full Wave)



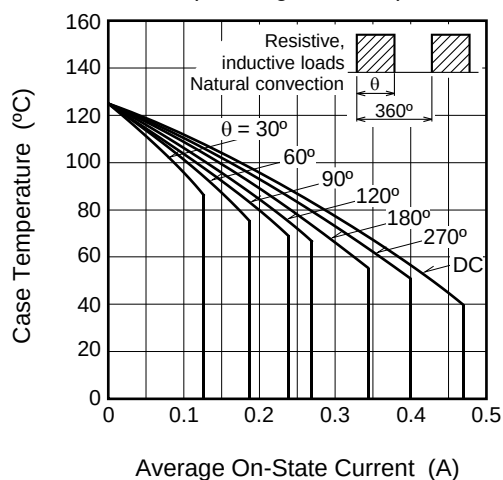
Allowable Case Temperature vs.
Average On-State Current
(Single-Phase Full Wave)

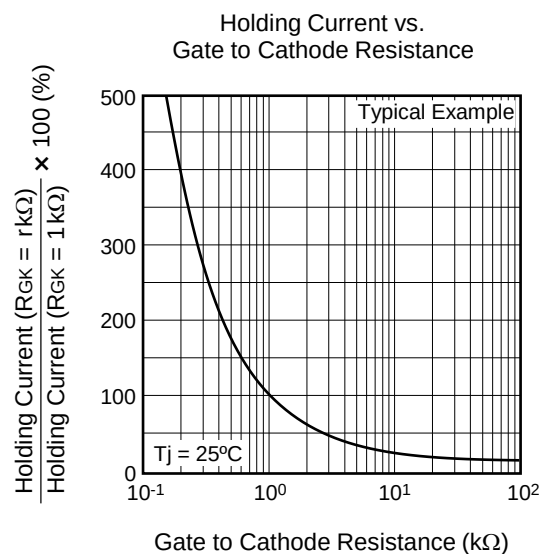
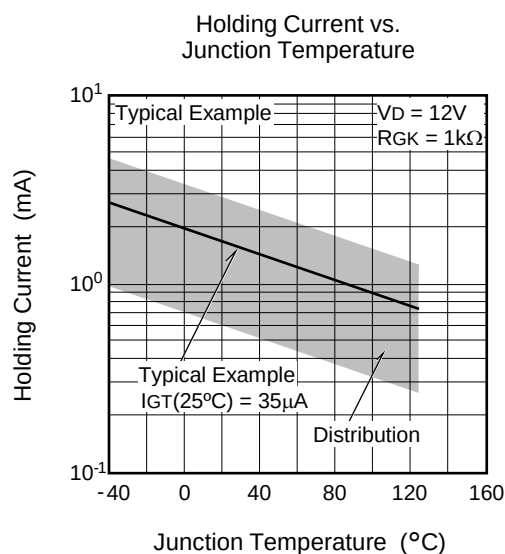
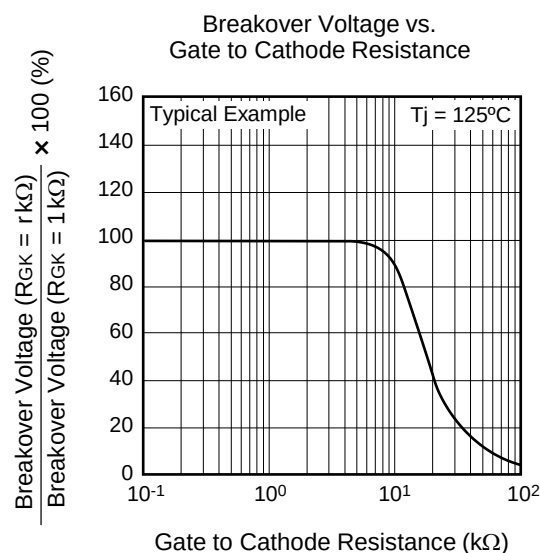
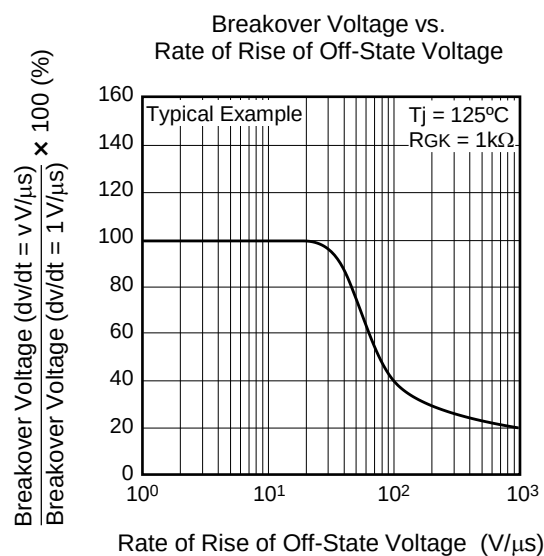
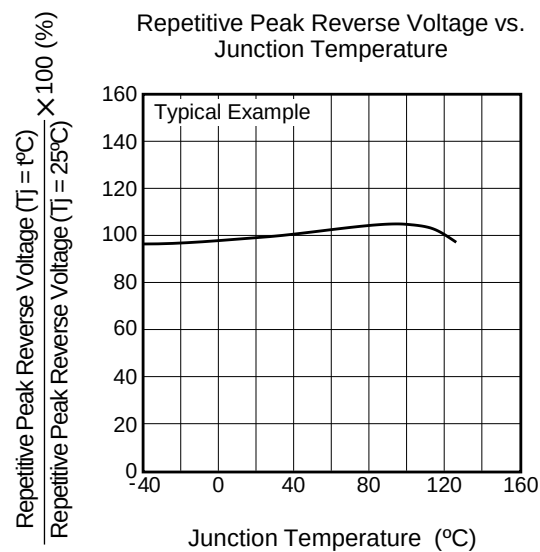
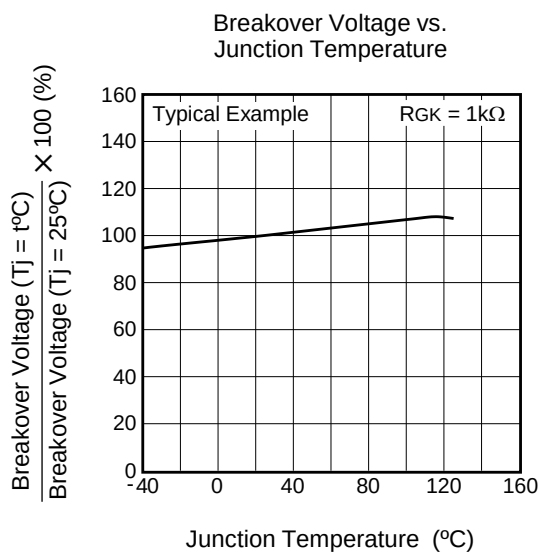


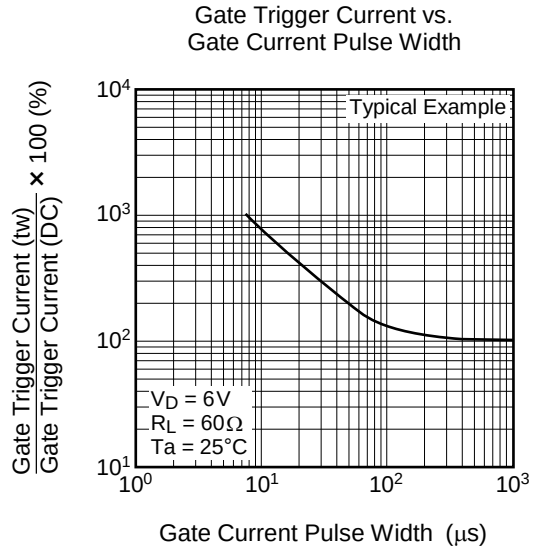
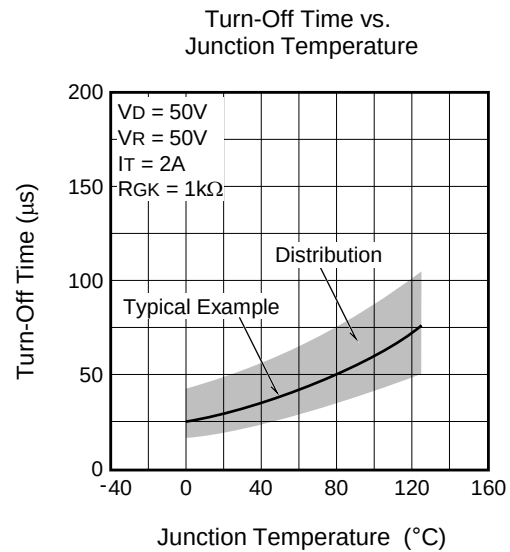
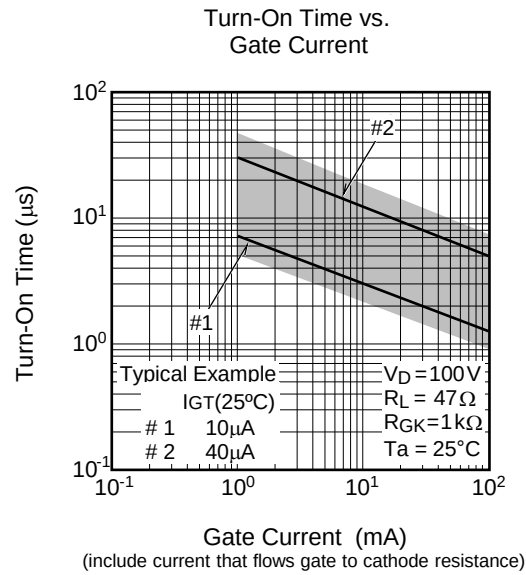
Maximum Average Power Dissipation
(Rectangular Wave)



Allowable Case Temperature vs.
Average On-State Current
(Rectangular Wave)

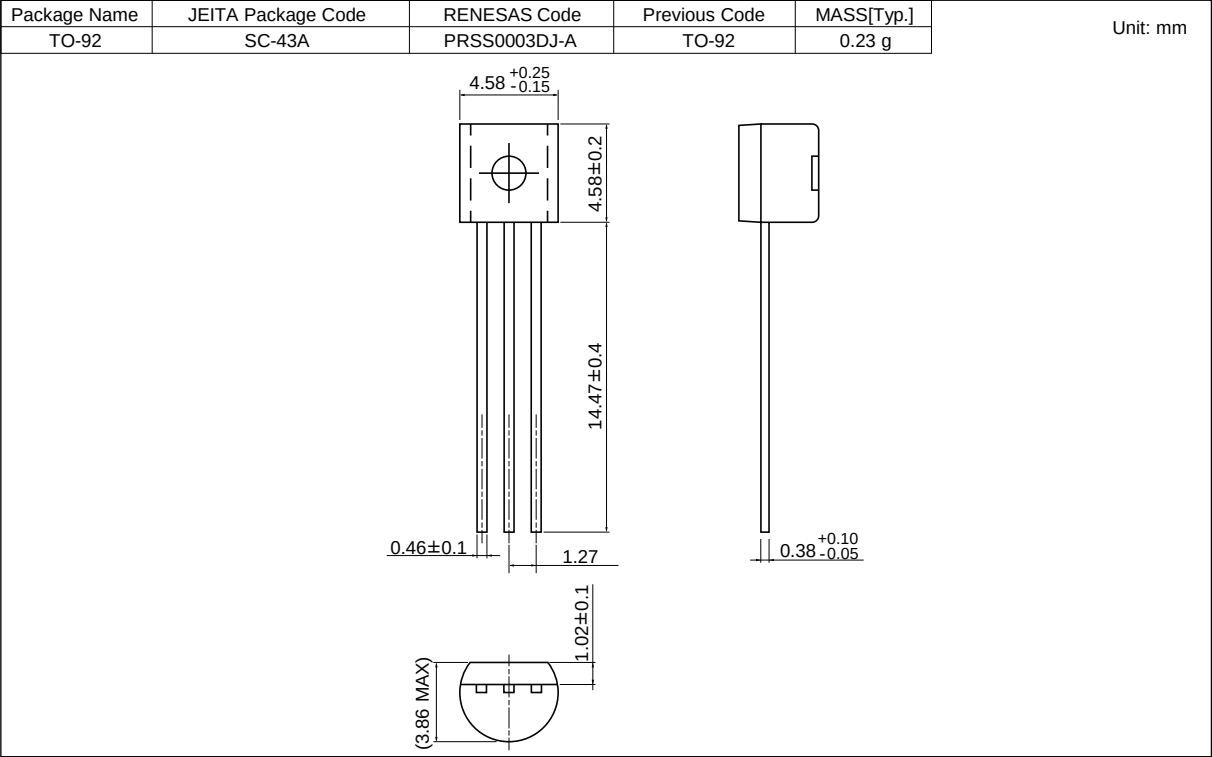




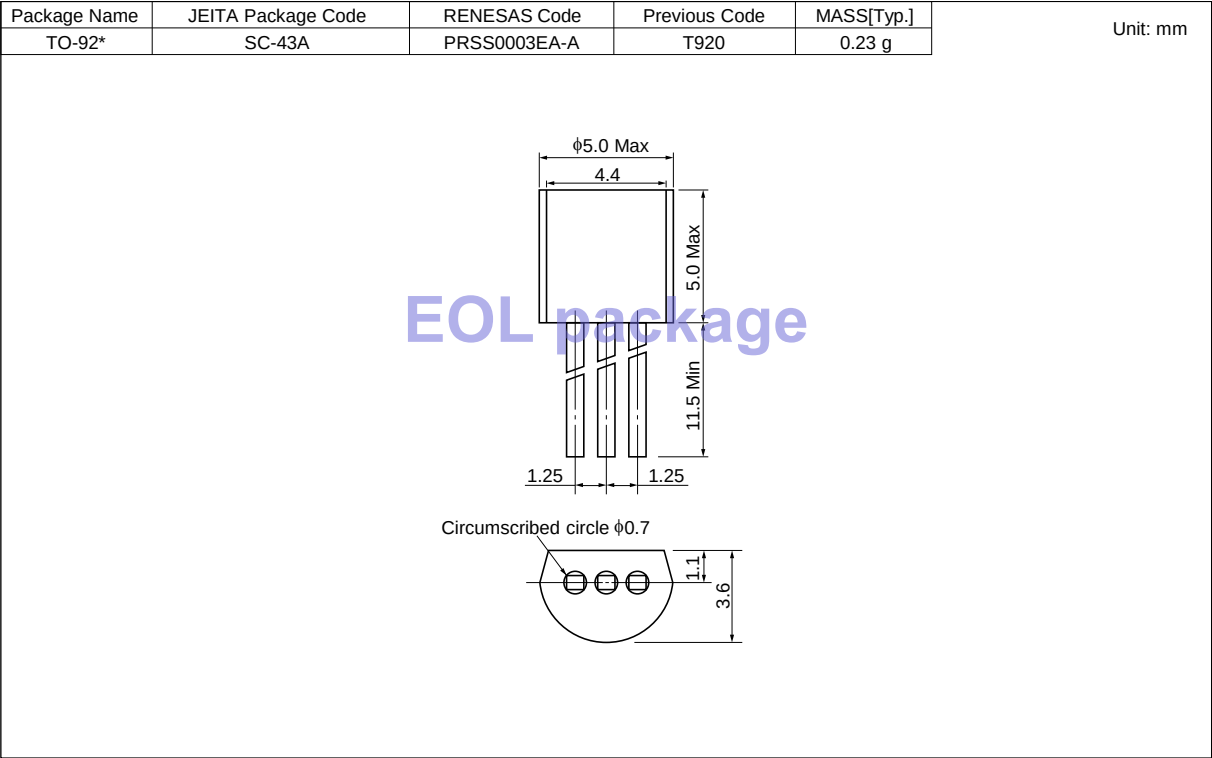


Package Dimensions

Ordering code: #BD0 <Active>



Ordering code: #B00 <Obsolete>



Ordering Information

Orderable Part Number	Package	Packing ^{Note4}	Quantity	Remark	Status
CR03AM-16A#BD0	TO-92	Plastic Bag	1000 pcs.	Straight type	Active
CR03AM-16A-□#BD0	TO-92	Plastic Bag	1000 pcs.	Straight type, □:IGT item	
CR03AM-16A-A6#BD0	TO-92	Plastic Bag	1000 pcs.	A6 Lead form	
CR03AM-16A-TB#BD0	TO-92	Adhesive Tape	2000 pcs.	A8 Lead form	
CR03AM-16A-□TB#BD0	TO-92	Adhesive Tape	2000 pcs.	A8 Lead form, □:IGT item	
CR03AM-16A#B00	TO-92*	Plastic Bag	500 pcs.	Straight type	Obsolete
CR03AM-16A-□#B00	TO-92*	Plastic Bag	500 pcs.	Straight type, □:IGT item	
CR03AM-16A-A6#B00	TO-92*	Plastic Bag	500 pcs.	A6 Lead form	
CR03AM-16A-TB#B00	TO-92*	Adhesive Tape	2000 pcs.	A8 Lead form	
CR03AM-16A-□TB#B00	TO-92*	Adhesive Tape	2000 pcs.	A8 Lead form, □:IGT item	

Note: 4. Please confirm the specification about the shipping in detail.

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